

### SMP80MC

## TRISIL™ for telecom equipment protection

### **Features**

- Bidirectional crowbar protection
- Voltage: range from 120 V to 320 V
- Low V<sub>BO</sub> / V<sub>R</sub> ratio
- Micro capacitance equal to 12 pF @ 50 V
- Low leakage current : I<sub>R</sub> = 2 µA max
- Holding current: I<sub>H</sub> = 150 mA min
- Repetitive peak pulse current :
- $I_{PP} = 80 \text{ A} (10/1000 \text{ µs})$

### **Main applications**

Any sensitive equipment requiring protection against lightning strikes and power crossing:

Terminals (phone, fax, modem...) and central office equipment

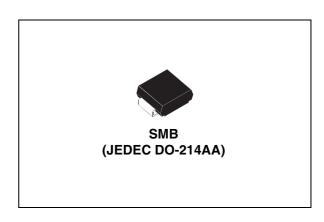
### Description

The SMP80MC is a series of micro capacitance transient surge arrestors designed for the protection of high debit rate communication equipment on CPE side. Its micro capacitance avoids any distortion of the signal and is compatible with digital transmission like ADSL2 and ADSL2+.

### **Benefits**

Trisils are not subject to ageing and provide a fail safe mode in short circuit for a better protection. They are used to help equipment to meet main standards such as UL1950, IEC950 / CSA C22.2 and UL1459. They have UL94 V0 approved resin. SMB package is JEDEC registered (DO-214AA). Trisils comply with the following standards GR-1089 Core, ITU-T-K20/K21, VDE0433, VDE0878, IEC61000-4-5 and FCC part 68.

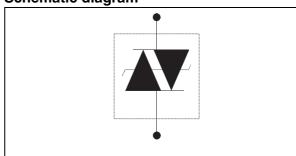
TM: TRISIL is a trademark of STMicroelectronics.



#### **Order codes**

| Part Number | Marking |
|-------------|---------|
| SMP80MC-120 | TP12    |
| SMP80MC-140 | TP14    |
| SMP80MC-160 | TP16    |
| SMP80MC-200 | TP20    |
| SMP80MC-230 | TP23    |
| SMP80MC-270 | TP27    |
| SMP80MC-320 | TP32    |

### Schematic diagram



Characteristics SMP80MC

## 1 Characteristics

Table 1. Complies with the following standards

| STANDARD                            | Peak Surge<br>Voltage<br>(V) | Waveform Voltage Required peak current (A) |  | Current<br>waveform    | Minimum serial resistor to meet standard ( $\Omega$ ) |
|-------------------------------------|------------------------------|--|--|------------------------|---|
| GR-1089 Core<br>First level         | 2500<br>1000                 | 2/10 μs<br>10/1000 μs                      | 500<br>100                                 | 2/10 μs<br>10/1000 μs  | 5<br>2.5  |
| GR-1089 Core<br>Second level        | 5000                         | 2/10 μs                                    | 500  | 2/10 μs                | 10  |
| GR-1089 Core<br>Intra-building      | 1500                         | 2/10 μs                                    | 100  | 2/10 μs                | 0   |
| ITU-T-K20/K21                       | 6000<br>1500                 | 10/700 μs                                  | 150<br>37.5                                | 5/310 µs               | 10<br>0   |
| ITU-T-K20<br>(IEC61000-4-2)         | 8000<br>15000                | 1/60 ns                                    | ESD contact discharge<br>ESD air discharge |                        | 0<br>0  |
| VDE0433                             | 4000<br>2000                 | 10/700 μs                                  | 100<br>50                                  | 5/310 µs               | 0<br>0  |
| VDE0878                             | 4000<br>2000                 | 1.2/50 µs                                  | 100<br>50                                  | 1/20 µs                | 0<br>0  |
| IEC61000-4-5                        | 4000<br>4000                 | 10/700 μs<br>1.2/50 μs                     | 100<br>100                                 | 5/310 μs<br>8/20 μs    | 0<br>0  |
| FCC Part 68, lightning surge type A | 1500<br>800                  | 10/160 μs<br>10/560 μs                     | 200<br>100                                 | 10/160 μs<br>10/560 μs | 2.5<br>0  |
| FCC Part 68, lightning surge type B | 1000                         | 9/720 µs                                   | 25   | 5/320 µs               | 0   |

Table 2. Absolute ratings  $(T_{amb} = 25^{\circ} C)$ 

| Symbol           | Parameter   | Conditions  | Value | Unit             |  |  |
|------------------|---|-------------|-------|------------------|--|--|
|                  |   | 10/1000 μs  | 80    |                  |  |  |
|                  |   | 8/20 µs     | 200   |                  |  |  |
|                  |   | 10/560 μs   | 100   |                  |  |  |
| IPP              | Repetitive peak pulse current (see Figure 1)            | 5/310 µs    | 120   | Α                |  |  |
|                  |   | 10/160 μs   | 150   |                  |  |  |
|                  |   | 1/20 µs     | 200   |                  |  |  |
|                  |   | 2/10 μs     | 250   |                  |  |  |
| I <sub>FS</sub>  | Fail-safe mode : maximum current (1)                    | 8/20 μs     | 5     | kA               |  |  |
|                  |   | t = 0.2 s   | 14    |                  |  |  |
| I                | Non repetitive surge peak on-state current              | t = 1 s     | 8     | Α                |  |  |
| ITSM             | (sinusoidal)  | t = 2 s     | 6.5   |                  |  |  |
|                  |   | t = 15 mn   | 2     |                  |  |  |
| l <sup>2</sup> t | I <sup>2</sup> t value for fusing                       | t = 16.6 ms | 7.5   | A <sup>2</sup> s |  |  |
| 1 (              | I t value for fushing                                   | 7.8         | A 5   |                  |  |  |
| T <sub>stg</sub> | Storage temperature range                               | -55 to 150  | ° C   |                  |  |  |
| T <sub>j</sub>   | Maximum junction temperature                            | 150         |       |                  |  |  |
| TL               | Maximum lead temperature for soldering during 10 s. 260 |             |       |                  |  |  |

<sup>1.</sup> in fail safe mode, the device acts as a short circuit

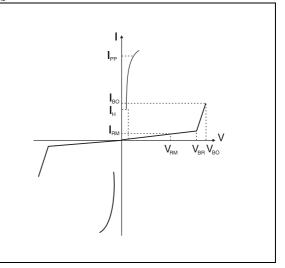
SMP80MC Characteristics

Table 3. Thermal resistances

| Symbol               | Parameter  | Value | Unit  |
|----------------------|--|-------|-------|
| R <sub>th(j-a)</sub> | Junction to ambient (with recommended footprint) | 100   | ° C/W |
| R <sub>th(j-l)</sub> | Junction to leads                                | 20    | ° C/W |

**Table 4.** Electrical characteristics  $(T_{amb} = 25^{\circ} C)$ 

| Symbol          | Parameter                         |  |
|-----------------|-----------------------------------|--|
| V <sub>RM</sub> | Stand-off voltage                 |  |
| V <sub>BR</sub> | Breakdown voltage                 |  |
| V <sub>BO</sub> | Breakover voltage                 |  |
| I <sub>RM</sub> | Leakage current                   |  |
| I <sub>PP</sub> | Peak pulse current                |  |
| I <sub>BO</sub> | Breakover current                 |  |
| IH              | Holding current                   |  |
| V <sub>R</sub>  | Continuous reverse voltage        |  |
| I <sub>R</sub>  | Leakage current at V <sub>R</sub> |  |
| С               | Capacitance                       |  |



|             | I <sub>RM</sub> @ | V <sub>RM</sub> | I <sub>R</sub> @ | V <sub>R</sub> <sup>(1)</sup> | Dynamic V <sub>BO</sub> <sup>(2)</sup> |      | atic<br>I <sub>BO</sub> (3) | I <sub>H</sub> <sup>(4)</sup> | C <sup>(5)</sup> | C <sup>(6)</sup> |
|-------------|-------------------|-----------------|------------------|-------------------------------|--|------|-----------------------------|-------------------------------|------------------|------------------|
| Types       | max.              |                 | max.             |                               | max.                                   | max. | max.                        | min.                          | typ.             | typ.             |
|             | μA                | V               | μΑ               | V                             | v                                      | ٧    | mA                          | mA                            | pF               | pF               |
| SMP80MC-120 |                   | 108             |                  | 120                           | 155                                    | 155  |                             |                               |                  |                  |
| SMP80MC-140 |                   | 126             |                  | 140                           | 180                                    | 180  |                             |                               |                  |                  |
| SMP80MC-160 |                   | 144             |                  | 160                           | 205                                    | 205  |                             |                               |                  |                  |
| SMP80MC-200 | 2                 | 180             | 5                | 200                           | 255                                    | 255  | 800                         | 150                           | 12               | 25               |
| SMP80MC-230 |                   | 207             |                  | 230                           | 295                                    | 295  |                             |                               |                  |                  |
| SMP80MC-270 |                   | 243             |                  | 270                           | 345                                    | 345  |                             |                               |                  |                  |
| SMP80MC-320 |                   | 290             |                  | 320                           | 400                                    | 400  |                             |                               |                  |                  |

- 1.  $I_R$  measured at  $V_R$  guarantee  $V_{BR}$  min  $\geq VR$
- 2. See Figure 9 functional test circuit 1
- 3. See Figure 10 test circuit 2
- 4. See Figure 11 functional holding current test circuit 3
- 5.  $V_R = 50 \text{ V bias}, V_{RMS} = 1 \text{ V}, F = 1 \text{ MHz}$
- 6.  $V_R = 2 V \text{ bias}, V_{RMS} = 1 V, F = 1 MHz$

Characteristics SMP80MC

Figure 1. Pulse waveform

Repetitive peak pulse current tr = rise time (µs) tp = pulse duration time (µs)

Figure 2. Non repetitive surge peak on-state current versus overload duration

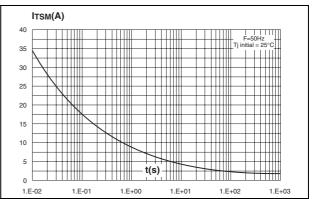
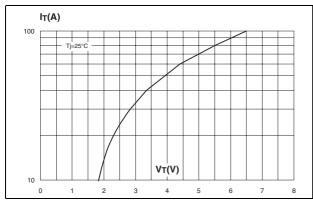


Figure 3. On-state voltage versus on-state current (typical values)

Figure 4. Relative variation of holding current versus junction temperature



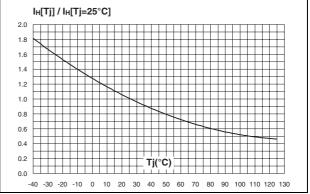
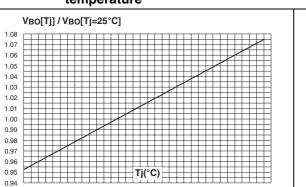
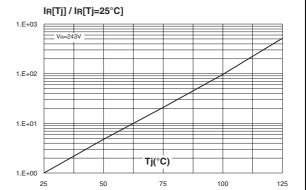


Figure 5. Relative variation of breakover voltage versus junction temperature



-40 -30 -20 -10 0 10 20 30 40 50 60 70 80 90 100 110 120 130

Figure 6. Relative variation of leakage current versus junction temperature (typical values)



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Figure 7. Variation of thermal impedance junction to ambient versus pulse duration (Printed circuit board FR4, SCu=35µm, recommended pad layout)

Figure 8. Relative variation of junction capacitance versus reverse voltage applied (typical values)

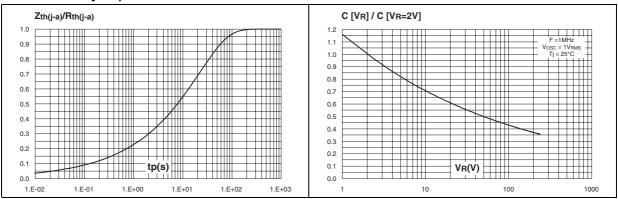
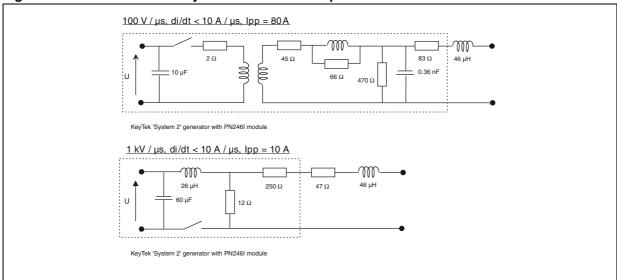


Figure 9. Test circuit 1 for dynamic IBO and VBO parameters



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Figure 10. Test circuit 2 for IBO and VBO parameters

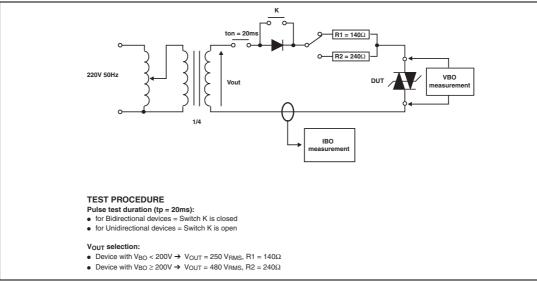
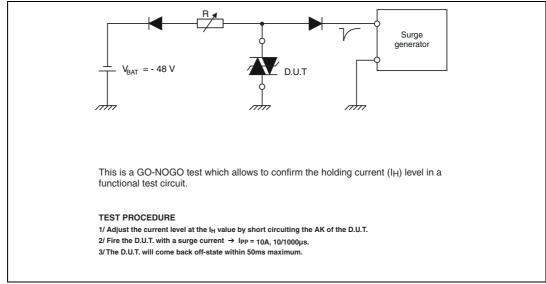
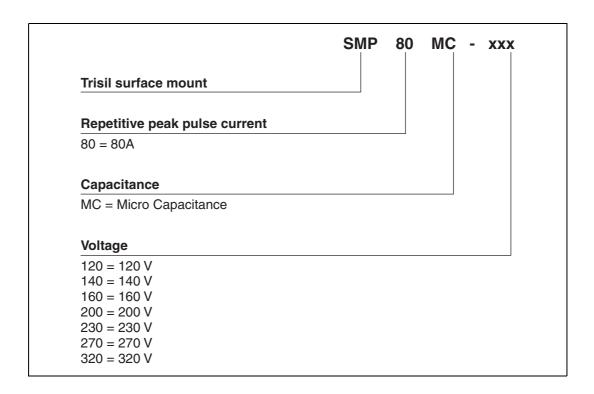


Figure 11. Test circuit 3 for dynamic IH parameter



## 2 Ordering Information Scheme



Package information SMP80MC

## 3 Package information

Epoxy meets UL94, V0

Table 5. SMB dimensions

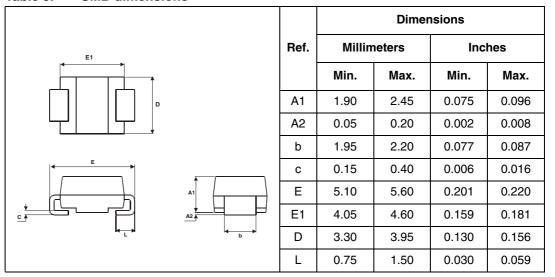
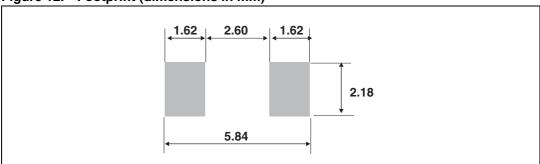


Figure 12. Footprint (dimensions in mm)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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# 4 Ordering information

| Part Number | Marking | Package | Weight | Base qty | Delivery mode |
|-------------|---------|---------|--------|----------|---------------|
| SMP80MC-120 | TP12    |         |        |          |               |
| SMP80MC-140 | TP14    |         |        |          |               |
| SMP80MC-160 | TP16    |         |        |          |               |
| SMP80MC-200 | TP20    | SMB     | 0.11 g | 2500     | Tape and reel |
| SMP80MC-230 | TP23    |         |        |          |               |
| SMP80MC-270 | TP27    |         |        |          |               |
| SMP80MC-320 | TP32    |         |        |          |               |

# 5 Revision history

| Date           | Revision | Description of Changes                                      |
|----------------|----------|---|
| September-2001 | 1        | First issue.  |
| 11-May-2005    | 2        | New types introduction.                                     |
| 20-Jun-2005    | 3        | Qualification of new types                                  |
| 18-Jan-2007    | 4        | Reformatted to current standards. Added product SMP80MC-320 |

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